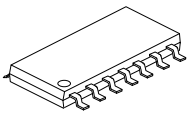
U74AHCT08

CMOS IC

QUADRUPLE 2-INPUT POSITIVE-AND GATE



SOP-14

■ DESCRIPTION

The **U74AHCT08** is a quadruple 2-input AND gate which performs the function Y=A*B or $Y=\overline{\overline{A}+\overline{B}}$.

■ FEATURES

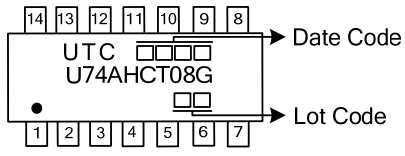
* Low Power Dissipation: I_{CC} = 2.0 μA (Max.)
* High Speed: t_{PD} = 5ns (Typ.)
* High Noise Immunity

■ ORDERING INFORMATION

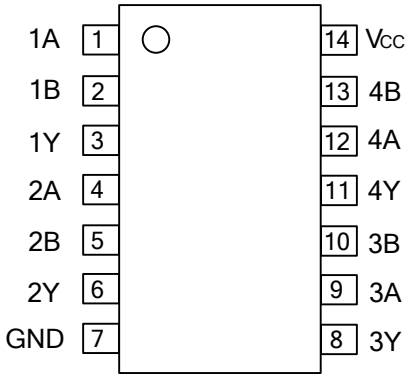
Ordering Number	Package	Packing
U74AHCT08G-S14-R	SOP-14	Tape Reel

U74AHCT08G-S14-R (1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) S14: SOP-14 (3) G: Halogen Free and Lead Free

■ MARKING



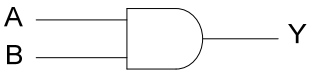
■ PIN CONFIGURATION



■ FUNCTION TABLE (Each Gate)

INPUTS		OUTPUT
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

■ LOGIC DIAGRAM (Positive Logic)



Logic symbol

IEC symbol

■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)(Note 2)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5~7	V
Input Voltage	V_{IN}	-0.5~7	V
Output Voltage	V_{OUT}	-0.5~V_{CC}+0.5	V
Input Clamp Current	I_{IK}	-20	mA
Output Clamp Current	I_{OK}	±20	mA
Output Current	I_{OUT}	±25	mA
V_{CC} or GND Current	I_{CC}	±50	mA
Storage Temperature	T_{STG}	-65 ~ +150	°C

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		4.5		5.5	V
Input Voltage	V_{IN}		0		5.5	V
Output Voltage	V_{OUT}		0		V_{CC}	V
Input Transition Rise or Fall Rate	t_R / t_F	V_{CC}=5.0+0.5V			20	ns/V
Ambient Operating Temperature	T_{OPR}		-40		85	°C

■ STATIC CHARACTERISTICS (T_A=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-Level Input Voltage	V_{IH}	V_{CC} = 4.5~5.5 V	2.0			V
Low-Level Input Voltage	V_{IL}	V_{CC} = 4.5~5.5 V			0.8	V
High-Level Output Voltage	V_{OH}	V_{CC} = 4.5V, I_{OH} = -50 μA	4.4	4.5		V
		V_{CC} = 4.5V, I_{OH} = -8 mA	3.94			
Low-Level Output Voltage	V_{OL}	V_{CC} = 4.5V, I_{OL} = 50μA			0.1	V
		V_{CC} = 4.5V, I_{OL} = 8 mA			0.36	
Input Leakage Current	$I_{I(LEAK)}$	V_{CC} = 5.5V, V_{IN} = V_{CC} or GND			±0.1	μA
Quiescent Supply Current	I_Q	V_{CC} = 5.5V, V_{IN} = V_{CC} or GND, I_{OUT} = 0			2	μA
Additional quiescent Supply Current	ΔI_Q	V_{CC} = 5.5V, V_{IN} = 3.4V; other input at V_{CC} or GND; I_{OUT}=0			1.35	mA
Input Capacitance	C_{IN}	V_{CC} = 5V, V_{IN} = V_{CC} or GND		4	10	pF

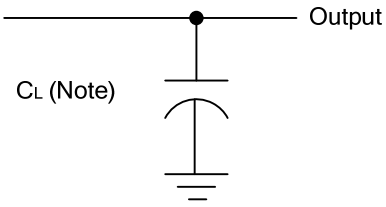
■ DYNAMIC CHARACTERISTICS (t_R, t_F ≤ 3 ns;)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Propagation delay from input (A and B) to output (Y)	t_{PLH}	V_{CC} =5±0.5 V, C_L=15 pF		5	6.9	ns
	t_{PHL}			5	6.9	
	t_{PLH}	V_{CC} =5±0.5 V, C_L=50 pF		5.5	7.9	
	t_{PHL}			5.5	7.9	

■ OPERATING CHARACTERISTICS (V_{CC} = 5V; T_A = 25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	TYP	UNIT
Power Dissipation Capacitance	C_{PD}	No load, f=1MHz	18	pF

■ TEST CIRCUIT AND WAVEFORMS



Note : CL includes probe and jig capacitance.